

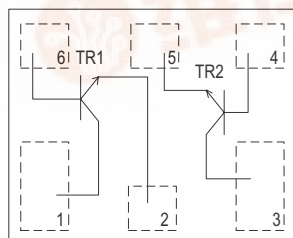
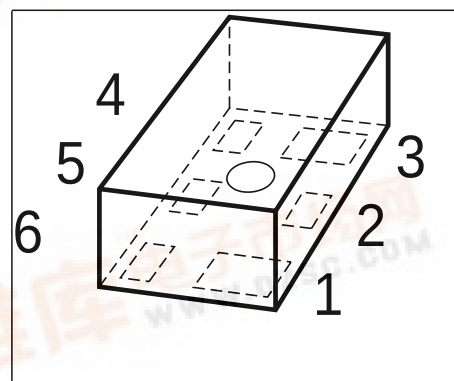


## BFS466L6

### NPN Silicon RF TWIN Transistor

Preliminary data

- Low voltage/ low current applications
- Ideal for VCO modules and low noise amplifiers
- Low noise figure: TR1: 1.1dB at 1.8 GHz  
TR2: 1.0 dB at 1.8 GHz
- World's smallest SMD 6-pin leadless package
- Built in 2 transistors (TR1: die as BFR460L3,  
TR2: die as BFR360L3)



**ESD:** Electrostatic discharge sensitive device, observe handling precaution!

| Type     | Marking | Pin Configuration |      |      |      |      |      | Package  |
|----------|---------|-------------------|------|------|------|------|------|----------|
| BFS466L6 | AC      | 1=C1              | 2=E1 | 3=C2 | 4=B2 | 5=E2 | 6=B1 | TSLP-6-1 |

### Maximum Ratings

| Parameter                 | Symbol    | Value | Unit |
|---------------------------|-----------|-------|------|
| Collector-emitter voltage | $V_{CEO}$ |       | V    |
| TR1                       |           | 4.5   |      |
| TR2                       |           | 6     |      |
| Collector-emitter voltage | $V_{CES}$ |       |      |
| TR1                       |           | 15    |      |
| TR2                       |           | 15    |      |
| Collector-base voltage    | $V_{CBO}$ |       |      |
| TR1                       |           | 15    |      |
| TR2                       |           | 15    |      |
| Emitter-base voltage      | $V_{EBO}$ |       |      |
| TR1                       |           | 1.5   |      |
| TR2                       |           | 2     |      |
| Collector current         | $I_C$     |       | mA   |
| TR1                       |           | 50    |      |
| TR2                       |           | 35    |      |

**Maximum Ratings**

| Parameter                             | Symbol    | Value       | Unit             |
|---------------------------------------|-----------|-------------|------------------|
| Base current                          | $I_B$     |             | mA               |
| TR1                                   |           | 5           |                  |
| TR2                                   |           | 4           |                  |
| Total power dissipation <sup>1)</sup> | $P_{tot}$ |             | mW               |
| TR1, $T_S \leq 104^\circ\text{C}$     |           | 200         |                  |
| TR2, $T_S \leq 102^\circ\text{C}$     |           | 210         |                  |
| Junction temperature                  | $T_j$     |             | $^\circ\text{C}$ |
| TR1                                   |           | 150         |                  |
| TR2                                   |           | 150         |                  |
| Ambient temperature                   | $T_A$     |             |                  |
| TR1                                   |           | -65 ... 150 |                  |
| TR2                                   |           | -65 ... 150 |                  |
| Storage temperature                   | $T_{stg}$ |             |                  |
| TR1                                   |           | -65 ... 150 |                  |
| TR2                                   |           | -65 ... 150 |                  |

**Thermal Resistance**

| Parameter                                | Symbol     | Value      | Unit |
|------------------------------------------|------------|------------|------|
| Junction - soldering point <sup>2)</sup> | $R_{thJS}$ |            | K/W  |
| TR1                                      |            | $\leq 230$ |      |
| TR2                                      |            | $\leq 230$ |      |

<sup>1)</sup>  $T_S$  is measured on the collector lead at the soldering point to the pcb

<sup>2)</sup> For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                                                                                                                    | Symbol        | Values   |            |            | Unit          |
|------------------------------------------------------------------------------------------------------------------------------|---------------|----------|------------|------------|---------------|
|                                                                                                                              |               | min.     | typ.       | max.       |               |
| DC Characteristics                                                                                                           |               |          |            |            |               |
| Collector-emitter breakdown voltage<br>TR1, $I_C = 1\text{ mA}$ , $I_B = 0$<br>TR2, $I_C = 1\text{ mA}$ , $I_B = 0$          | $V_{(BR)CEO}$ | 4.5<br>6 | 5<br>9     | -<br>-     | V             |
| Collector-emitter cutoff current<br>TR1, $V_{CE} = 15\text{ V}$ , $V_{BE} = 0$<br>TR2, $V_{CE} = 15\text{ V}$ , $V_{BE} = 0$ | $I_{CES}$     | -<br>-   | -<br>-     | 10<br>10   | $\mu\text{A}$ |
| Collector-base cutoff current<br>TR1, $V_{CB} = 5\text{ V}$ , $I_E = 0$<br>TR2, $V_{CB} = 5\text{ V}$ , $I_E = 0$            | $I_{CBO}$     | -<br>-   | -<br>-     | 100<br>100 | nA            |
| Emitter-base cutoff current<br>TR1, $V_{EB} = 0,5\text{ V}$ , $I_C = 0$<br>TR2, $V_{EB} = 1\text{ V}$ , $I_C = 0$            | $I_{EBO}$     | -<br>-   | -<br>-     | 1<br>1     | $\mu\text{A}$ |
| DC current gain<br>TR1, $I_C = 20\text{ mA}$ , $V_{CE} = 3\text{ V}$<br>TR2, $I_C = 20\text{ mA}$ , $V_{CE} = 3\text{ V}$    | $h_{FE}$      | -<br>90  | 130<br>130 | -<br>160   | -             |

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                                                                                                                                                                    | Symbol   | Values   |              |             | Unit |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|----------|--------------|-------------|------|
|                                                                                                                                                                              |          | min.     | typ.         | max.        |      |
| AC Characteristics (verified by random sampling)                                                                                                                             |          |          |              |             |      |
| Transition frequency<br>TR1, $I_C = 30\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $f = 1\text{ GHz}$<br>TR2, $I_C = 15\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $f = 1\text{ GHz}$     | $f_T$    | 16<br>11 | 22<br>14     | -<br>-      | GHz  |
| Collector-base capacitance<br>TR1, $V_{CB} = 3\text{ V}$ , $f = 1\text{ MHz}$ , emitter grounded<br>TR2, $V_{CB} = 5\text{ V}$ , $f = 1\text{ MHz}$ , emitter grounded       | $C_{cb}$ | -<br>-   | 0.33<br>0.3  | 0.5<br>0.45 | pF   |
| Collector emitter capacitance<br>TR1, $V_{CE} = 3\text{ V}$ , $f = 1\text{ MHz}$ , base grounded<br>TR1, $V_{CE} = 3\text{ V}$ , $f = 1\text{ MHz}$ , base grounded          | $C_{ce}$ | -<br>-   | 0.17<br>0.17 | -<br>-      |      |
| Emitter-base capacitance<br>TR1, $V_{EB} = 0,5\text{ V}$ , $f = 1\text{ MHz}$ , collector grounded<br>TR2, $V_{EB} = 0,5\text{ V}$ , $f = 1\text{ MHz}$ , collector grounded | $C_{eb}$ | -<br>-   | 0.57<br>0.48 | -<br>-      |      |

**Electrical Characteristics** at TA = 25°C, unless otherwise specified

| Parameter                                                                                                                   | Symbol            | Values |      |      | Unit |
|-----------------------------------------------------------------------------------------------------------------------------|-------------------|--------|------|------|------|
|                                                                                                                             |                   | min.   | typ. | max. |      |
| AC Characteristics (verified by random sampling)                                                                            |                   |        |      |      |      |
| Noise figure                                                                                                                | $F$               |        |      |      | dB   |
| TR1, $I_C=5\text{mA}$ , $V_{CE} = 3\text{ V}$ , $f = 1.8\text{ GHz}$ , $Z_S = Z_{\text{Sopt}}$                              |                   | -      | 1.1  | -    |      |
| TR1, $I_C=5\text{mA}$ , $V_{CE} = 3\text{ V}$ , $f = 3\text{ GHz}$ , $Z_S = Z_{\text{Sopt}}$                                |                   | -      | 1.4  | -    |      |
| TR2, $I_C=3\text{mA}$ , $V_{CE} = 3\text{ V}$ , $f = 1.8\text{ GHz}$ , $Z_S = Z_{\text{Sopt}}$                              |                   | -      | 1    | -    |      |
| TR2, $I_C=3\text{mA}$ , $V_{CE} = 3\text{ V}$ , $f = 3\text{ GHz}$ , $Z_S = Z_{\text{Sopt}}$                                |                   | -      | 1.4  | -    |      |
| Power gain, maximum available <sup>1)</sup>                                                                                 | $G_{\text{ma}}$   |        |      |      |      |
| TR1, $I_C = 20\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S=Z_{\text{Sopt}}$ , $Z_L=Z_{\text{Lopt}}$ ,<br>$f = 1.8\text{ GHz}$ |                   | -      | 14.5 | -    |      |
| TR1, $I_C = 20\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S=Z_{\text{Sopt}}$ , $Z_L=Z_{\text{Lopt}}$ ,<br>$f = 3\text{ GHz}$   |                   | -      | 10   | -    |      |
| TR2, $I_C = 15\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S=Z_{\text{Sopt}}$ , $Z_L=Z_{\text{Lopt}}$ ,<br>$f = 1.8\text{ GHz}$ |                   | -      | 14.5 | -    |      |
| TR2, $I_C = 15\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S=Z_{\text{Sopt}}$ , $Z_L=Z_{\text{Lopt}}$ ,<br>$f = 3\text{ GHz}$   |                   | -      | 10   | -    |      |
| Transducer gain                                                                                                             | $ S_{21e} ^2$     |        |      |      |      |
| TR1, $I_C = 20\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S = Z_L = 50\Omega$ ,<br>$f = 1.8\text{GHz}$                         |                   | -      | 12.5 | -    |      |
| TR1, $I_C = 20\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S = Z_L = 50\Omega$ ,<br>$f = 3\text{GHz}$                           |                   | -      | 9    | -    |      |
| TR2, $I_C = 15\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S = Z_L = 50\Omega$ ,<br>$f = 1.8\text{GHz}$                         |                   | -      | 12.5 | -    |      |
| TR2, $I_C = 15\text{ mA}$ , $V_{CE} = 3\text{ V}$ , $Z_S = Z_L = 50\Omega$ ,<br>$f = 3\text{GHz}$                           |                   | -      | 8.5  | -    |      |
| Third order intercept point at output <sup>2)</sup>                                                                         | $IP_3$            |        |      |      | dBm  |
| TR1, $V_{CE}=3\text{V}$ , $I_C=20\text{mA}$ , $Z_S=Z_L=50\Omega$ , $f=1.8\text{GHz}$                                        |                   | -      | 28   | -    |      |
| TR2, $V_{CE}=3\text{V}$ , $I_C=15\text{mA}$ , $Z_S=Z_L=50\Omega$ , $f=1.8\text{GHz}$                                        |                   | -      | 24.5 | -    |      |
| 1dB Compression point, at output                                                                                            | $P_{-1\text{dB}}$ |        |      |      |      |
| TR1, $I_C=20\text{mA}$ , $V_{CE}=3\text{V}$ , $Z_S=Z_L=50\Omega$ , $f=1.8\text{GHz}$                                        |                   | -      | 12   | -    |      |
| TR1, $I_C=15\text{mA}$ , $V_{CE}=3\text{V}$ , $Z_S=Z_L=50\Omega$ , $f=1.8\text{GHz}$                                        |                   | -      | 9    | -    |      |

<sup>1)</sup>  $G_{ma} = |S_{21e} / S_{12e}| (k \cdot (k^2 - 1)^{1/2})$ 
<sup>2)</sup>  $IP_3$  value depends on termination of all intermodulation frequency components.  
Termination used for this measurement is 50Ω from 0.1 MHz to 6 GHz